

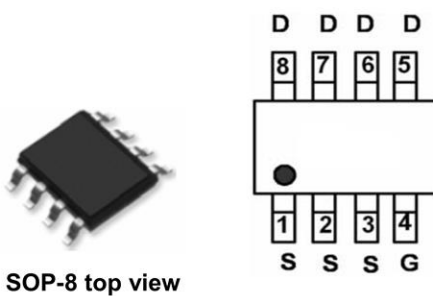
GENERAL FEATURES

- $V_{DS} = 30V, I_D = 12A$
- $R_{DS(ON)} < 12m\Omega @ V_{GS} = 10V$
- $R_{DS(ON)} < 16m\Omega @ V_{GS} = 4.5V$

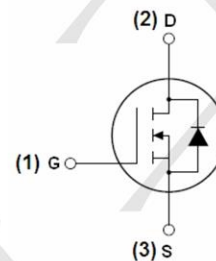
Application

- Battery protection
- Load switch

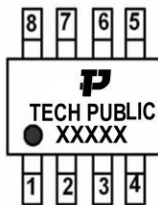
Package and Pin Configuration



Circuit diagram



Marking:



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“XXXXX” Marking ID (Please see the last page for details)

Absolute Maximum Ratings ($T_A = 25^\circ C$ unless otherwise noted)

| Parameter | Symbol | Limit | Unit |
|--|--------------------|------------|------------|
| Drain-Source Voltage | V_{DS} | 30 | V |
| Gate-Source Voltage | V_{GS} | ± 20 | V |
| Drain Current-Continuous | I_D | 12 | A |
| Drain Current-Continuous($T_C = 100^\circ C$) | $I_D(100^\circ C)$ | 6 | A |
| Pulsed Drain Current | I_{DM} | 50 | A |
| Maximum Power Dissipation | P_D | 2.5 | W |
| Operating Junction and Storage Temperature Range | T_J, T_{STG} | -55 To 150 | $^\circ C$ |

Thermal Characteristic

| | | | |
|--|-----------------|----|--------------|
| Thermal Resistance, Junction-to-Case ^(Note 2) | $R_{\theta JC}$ | 50 | $^\circ C/W$ |
|--|-----------------|----|--------------|

Electrical Characteristics (T_A=25°C unless otherwise noted)

| Parameter | Symbol | Condition | Min | Typ | Max | Unit |
|---|---------------------|--|-----|------|------|------|
| Off Characteristics | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V, I _D =250μA | 30 | - | - | V |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} =30V, V _{GS} =0V | - | - | 1 | μA |
| Gate-Body Leakage Current | I _{GSS} | V _{GS} =±20V, V _{DS} =0V | - | - | ±100 | nA |
| On Characteristics (Note 3) | | | | | | |
| Gate Threshold Voltage | V _{GS(th)} | V _{DS} =V _{GS} , I _D =250μA | 1 | 1.6 | 3 | V |
| Drain-Source On-State Resistance | R _{DS(on)} | V _{GS} =10V, I _D =10A | - | 8 | 12 | mΩ |
| | | V _{GS} =4.5V, I _D =8A | - | 11 | 16 | |
| Forward Transconductance | g _{FS} | V _{DS} =5V, I _D =10A | 15 | - | - | S |
| Dynamic Characteristics (Note 4) | | | | | | |
| Input Capacitance | C _{iss} | V _{DS} =15V, V _{GS} =0V, F=1.0MHz | - | 1550 | - | PF |
| Output Capacitance | C _{oss} | | - | 300 | - | PF |
| Reverse Transfer Capacitance | C _{rss} | | - | 180 | - | PF |
| Switching Characteristics (Note 4) | | | | | | |
| Turn-on Delay Time | t _{d(on)} | V _{DD} =25V, I _D =1A V _{GS} =10V, R _{GEN} =6Ω | - | 30 | - | nS |
| Turn-on Rise Time | t _r | | - | 20 | - | nS |
| Turn-Off Delay Time | t _{d(off)} | | - | 100 | - | nS |
| Turn-Off Fall Time | t _f | | - | 80 | - | nS |
| Total Gate Charge | Q _g | V _{DS} =15V, I _D =10A, V _{GS} =5V | - | 13 | - | nC |
| Gate-Source Charge | Q _{gs} | | - | 5.5 | - | nC |
| Gate-Drain Charge | Q _{gd} | | - | 3.5 | - | nC |
| Drain-Source Diode Characteristics | | | | | | |
| Diode Forward Voltage (Note 3) | V _{SD} | V _{GS} =0V, I _S =10A | - | - | 1.2 | V |
| Diode Forward Current (Note 2) | I _S | | - | - | 12 | A |

Typical Electrical and Thermal Characteristics (Curves)

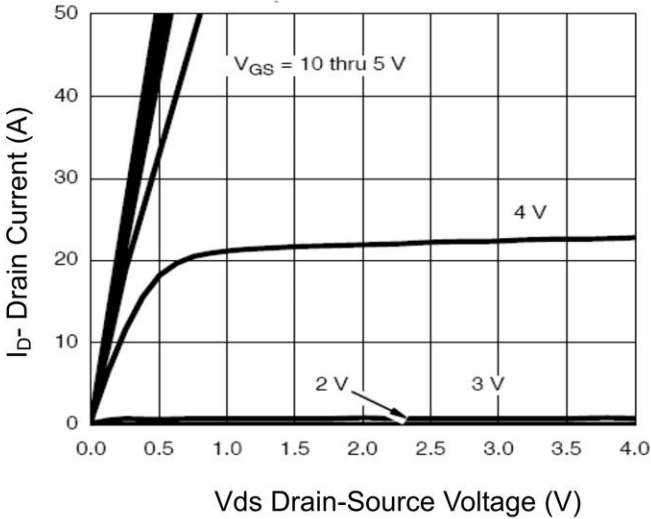


Figure 1 Output Characteristics

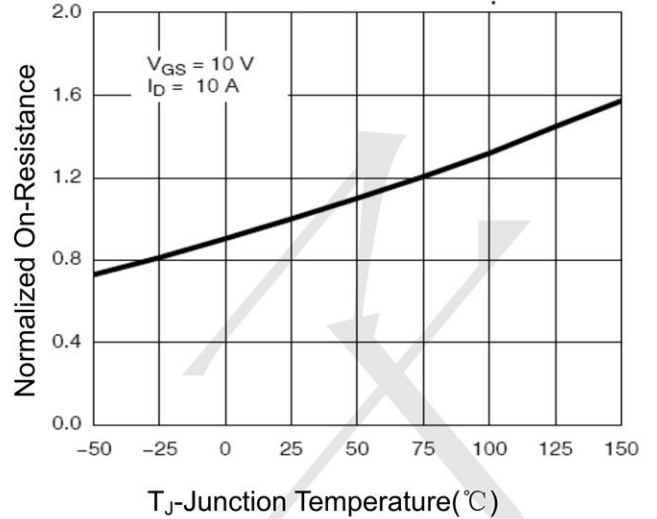


Figure 4 $R_{ds(on)}$ -Junction Temperature

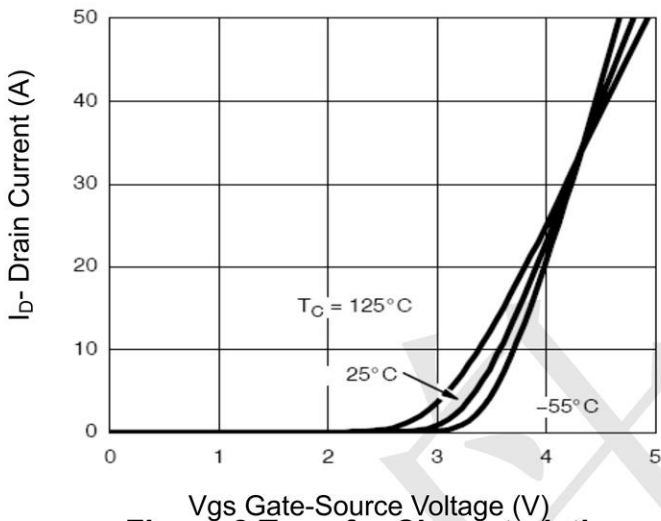


Figure 2 Transfer Characteristics

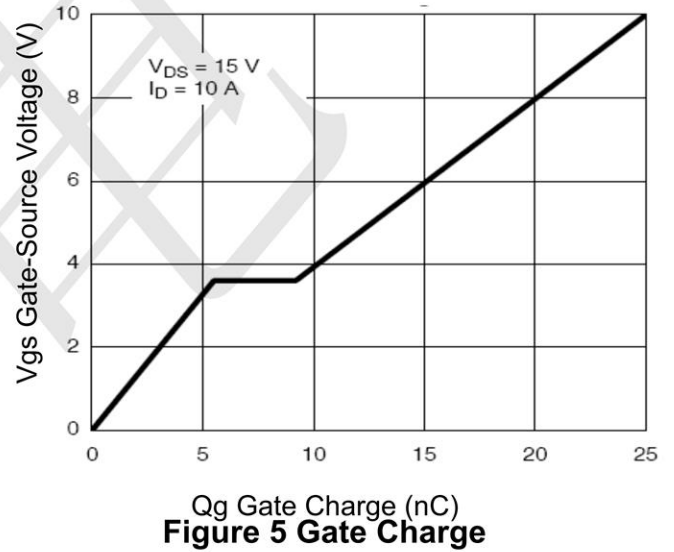


Figure 5 Gate Charge

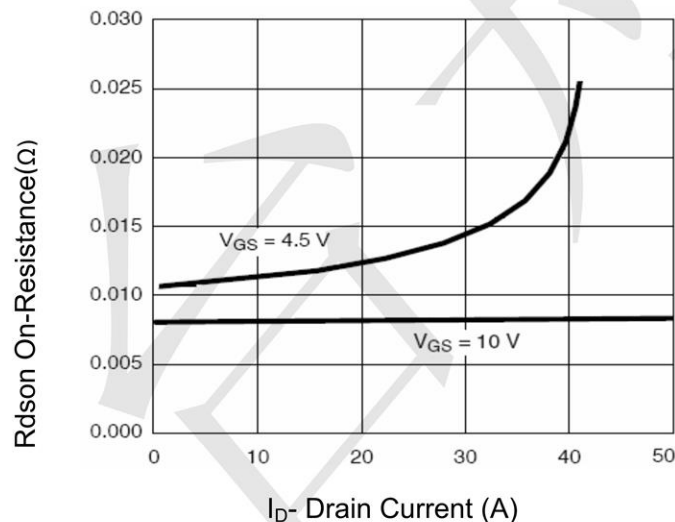


Figure 3 $R_{ds(on)}$ - Drain Current

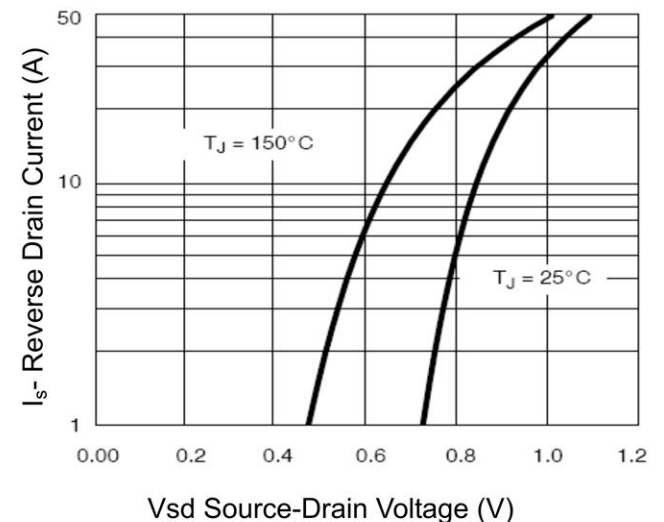
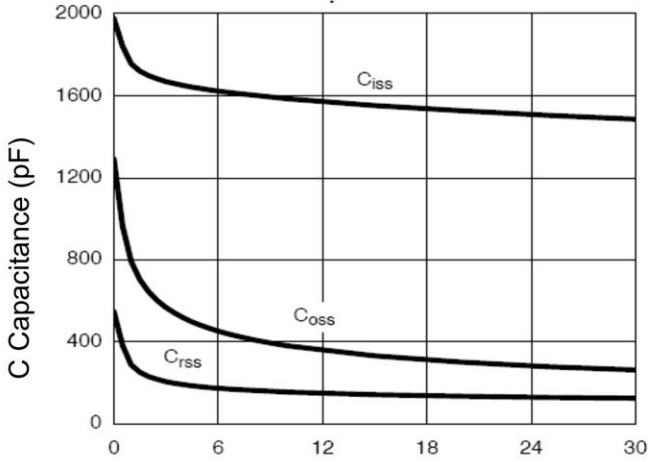
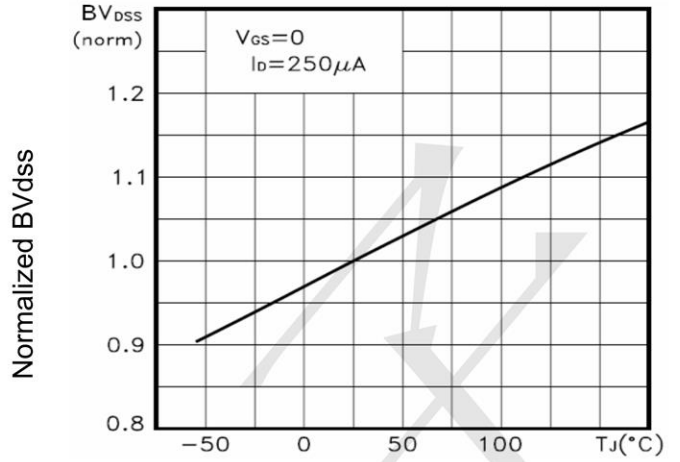


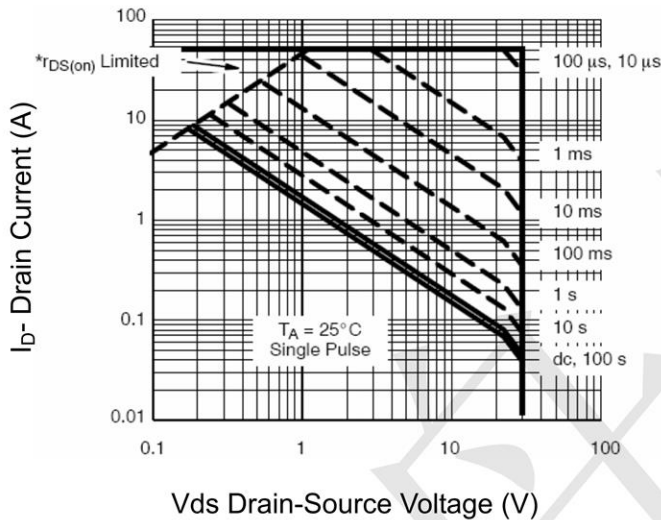
Figure 6 Source- Drain Diode Forward



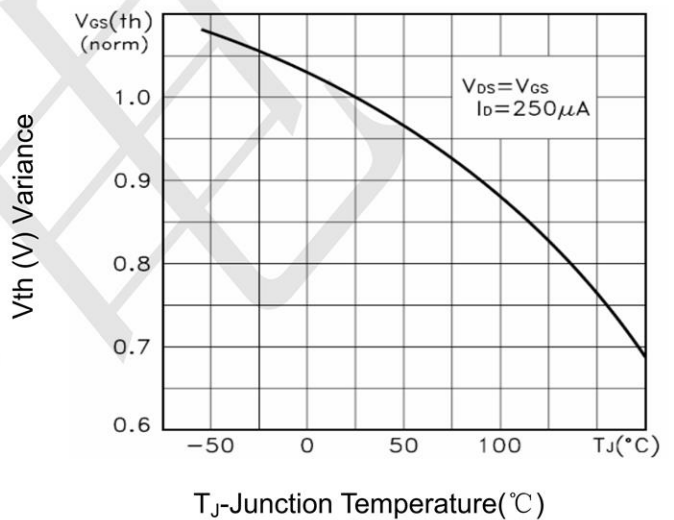
Vds Drain-Source Voltage (V)
Figure 7 Capacitance vs Vds



T_J-Junction Temperature(°C)
Figure 9 BV_{DSS} vs Junction Temperature



Vds Drain-Source Voltage (V)
Figure 8 Safe Operation Area



T_J-Junction Temperature(°C)
Figure 10 V_{GS(th)} vs Junction Temperature

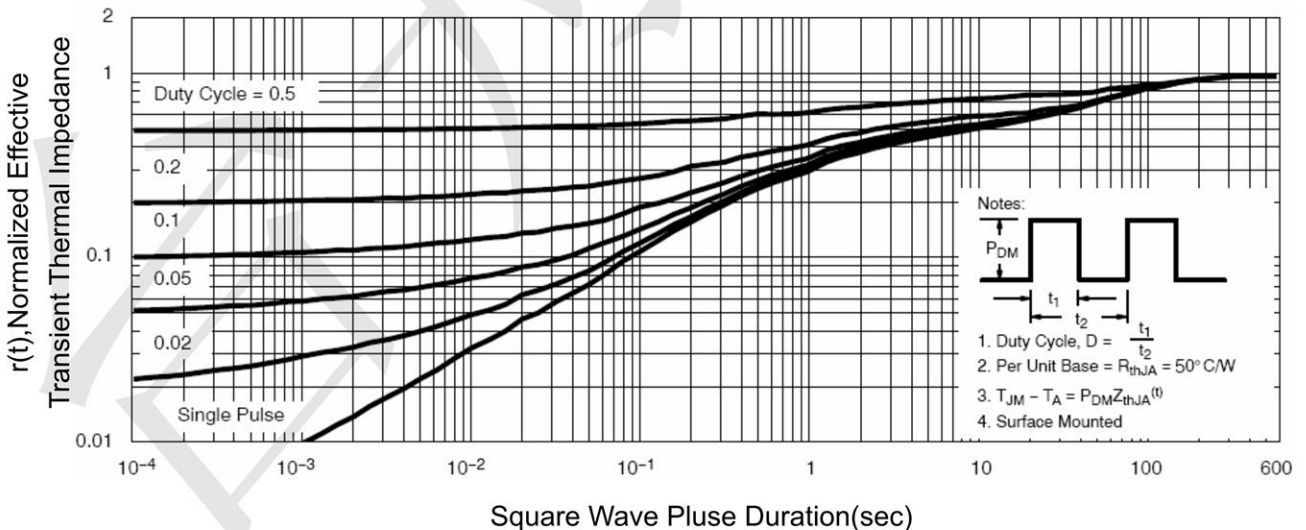
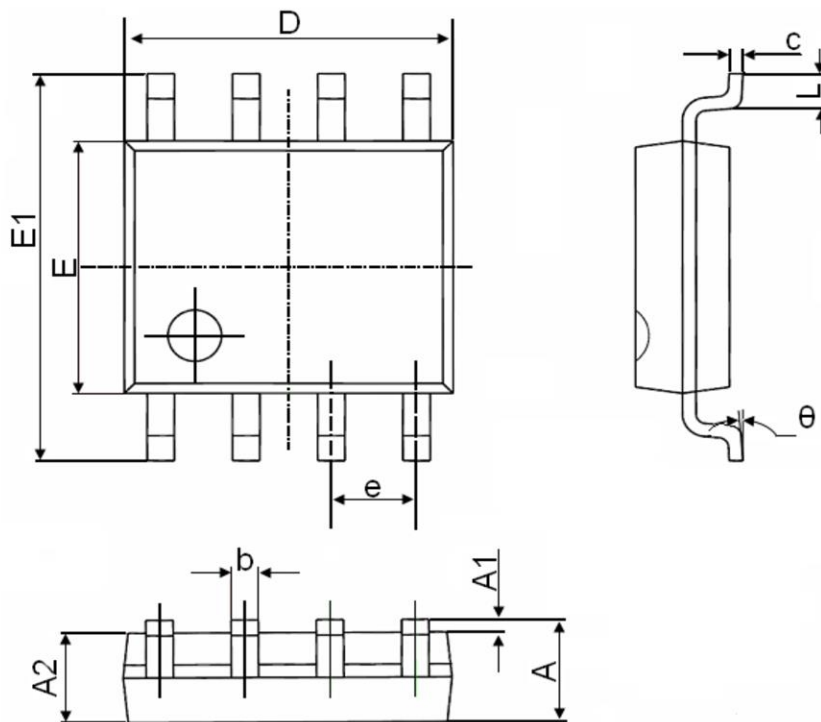


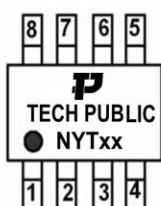
Figure 11 Normalized Maximum Transient Thermal Impedance

SOP-8 Package Information



| Symbol | Dimensions In Millimeters | | Dimensions In Inches | |
|----------|---------------------------|-------|----------------------|-------|
| | Min. | Max. | Min. | Max. |
| A | 1.350 | 1.750 | 0.053 | 0.069 |
| A1 | 0.100 | 0.250 | 0.004 | 0.010 |
| A2 | 1.350 | 1.550 | 0.053 | 0.061 |
| b | 0.330 | 0.510 | 0.013 | 0.020 |
| c | 0.170 | 0.250 | 0.006 | 0.010 |
| D | 4.700 | 5.100 | 0.185 | 0.200 |
| E | 3.800 | 4.000 | 0.150 | 0.157 |
| E1 | 5.800 | 6.200 | 0.228 | 0.244 |
| e | 1.270(BSC) | | 0.050(BSC) | |
| L | 0.400 | 1.270 | 0.016 | 0.050 |
| θ | 0° | 8° | 0° | 8° |

Marking:



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